Electronic Supplementary Information for

A Novel Energy Dependent Heterojunction of *p*-Semiconductor—Metal—*n*-Semiconductor for Selectively Steering Charge Flow in Z-scheme Photocatalyst

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Fig. S1 Structural illustration of CuO and CoO unit cells and their antiferromagnetic spin ordering, respectively. Arrows on the metal ions indicate the orientation of local magnetic moments.



Fig. S2 Calculated work functions of Pd (100) and Pd (111), consecutively.



Fig. S3 (a) neutral and $0.01e^+$ charge of Cu₂O (b) neutral and $0.5e^-$ charge of CuO (c) neutral and $0.01e^+$ charge of CoO and (d) neutral and $0.05e^-$ charge of WO₃.



Fig. S4 (a) neutral, $0.01e^+$, $0.02e^+$, $0.03e^+$, $0.04e^+$ and $0.05e^+$ charge of Cu₂O (b) neutral, $0.01e^-$, $0.02e^-$, $0.03e^-$, $0.04e^-$ and $0.05e^-$ charge of WO₃.



Fig. S5 (a) neutral,0.01 e^+ ,0.02 e^+ , 0.03 e^+ , 0.04 e^+ and 0.05 e^+ charge of Cu₂O (b) neutral,0.01 e^- , 0.02 e^- , 0.03 e^- , 0.04 e^- and 0.05 e^- charge of WO₃.



Fig. S6 (a) and (b) are differential charge densities at *p-m* junctions of Cu₂O(100)-Pd(cluster) and CoO(100)-Pd(cluster), respectively, with an iso-value of 0.004 eÅ⁻³. Yellow and blue bubbles represent electron accumulation and donation/depletion in space, respectively. Based on Bader charge analysis, the charge transfer from p-type semiconductors of Cu₂O(111) and CoO(100) to Pd cluster is 0.29 and 0.22 e⁻, respectively.



Fig. S7 Differential charge densities at *p-m-n* junctions of ternary CoO(100)-Pd(100)-WO₃(100) with an iso-value of 0.004 eÅ⁻³. Yellow and blue bubbles represent electron accumulation and donation/depletion in space, respectively.

	Parameter (Å)	Cal. $E_{g}(eV)$	Exp. $E_g(eV)$
Cu ₂ O	a=b=c=4.28	0.7	2.2
CuO	a=4.69, b=3.47, c=5.14	1.4	2.6
CoO	a=b=c=4.21	0.6	1.7
WO ₃	a=7.53, b=7.69, c=7.83	1.4	2.7
Pd	a=b=c=3.94		

Table S1. Calculated lattice parameters of unit cells and band gap (E_g) compared to experimental data.

Table S2. The position of Fermi level (E_F) *versus* vacuum energy level ($E_v=0$), parameters of slab models for semiconductors surface and Pd for building interface junctions.

	Parameter (Å)	$E_F(eV)$	Supercell	Matched with Pd	Mis-matching
Cu ₂ O(111	μ=6.09,υ=6.09	-4.74	2×2	4×4	8.3%, 8.3%
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CuO(010)	μ=5.18,υ=3.80	-6.53	3×2	4×2	2.0%, 2.5%
CoO(100)	μ=4.21,υ=4.21	-4.20	2×2	2×2	6.3%, 6.3%
WO ₃ (100)	μ=7.69,υ=7.83	-6.71	1×1	2×2	2.3%, 0.5%